

Synchronous Parallel kinetic Monte Carlo: Diffusion in Heterogeneous Systems

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We present a new algorithm that is the key component of our project aiming at a massively parallel off-lattice kinetic Monte Carlo code for heterogeneous systems that will extend the time scale limits of MD to study diffusion at interfaces in concentrated alloys

Motivation

Point defects - interface interactions

Segregation and precipitation at dislocations

Radiation Induced Segregation

Diffusional Creep

Bruemmer SM, et al. J. Nucl Mater 274:299-314

Coupling MD Lammers – Synchronous parallel kMC

- Set of possible events.
- Harmonic transition state theory.
- Particle rate: $\Gamma = \nu \exp(-E_{sp}/kT)$; $E_{sp} = E_0 + (E_r - E_0)/2$

Case Studies

001 Coherent Interface Fe-Cr

System tends to the equilibrium configuration

Short-Range Order kinetics in Fe-Cr

Significant difference in the Short-Range Ordering kinetics.

Vacancy Accumulation and Jog Formation on an edge dislocation dipole

Vacancies (red dots) are inserted at a rate of 10^3 V/A³s

MC steps = 1, T = 2.6×10^{-6} s
 MC steps = 4000, T = 3.4325×10^{-3} s
 MC steps = 10000, T = 5.0032×10^{-3} s

Diffusion in the presence of strain fields

Vacancy Flux around an edge dislocation dipole

Vacancies are less probable to be in regions under tension than in regions under compression

Vacancy Accumulation and Microstructure Evolution on a 2 degrees Twist Boundary in Fe

Dose rate = 10^{-2} V/A³s, $t_c = 1.265e-03$ s
 Dose rate = 3.10^{-2} V/A³s, $t_c = 4.244e-05$ s
 Dose rate = 10^{-3} V/A³s, $t_c = 8.500e-06$ s

Technological Issues

- Finding possible events.
 - o In crystalline structures, localization of the walkers will help in finding the transition paths.
 - o For highly heterogeneous systems, tools like ART (activation-relaxation technique), TAD (temperature accelerated dynamics) or the dimer method may have to be explored.
- Calculate their rates accurately.
 - o To achieve it, the right number for the pre-exponential factor and for the activation barrier will have to be calculated.
- Massive Parallelization.
 - o kMC is tricky to parallelize. Synchronous parallel kMC.

Synchronous Parallel kinetic Monte Carlo Algorithm

Now, for parallel kMC, perform K (d) domain partitions and construct frequency lines:

The $r_{i,j}$ are the "dummy" rates (no event) that ensure synchronicity:

$$r_{max} = r_i + r_{i,j}$$

$$R_{tot} \leq \sum_i (r_i + r_{i,j}) \leq K r_{max}$$

For optimum scalability, perform domain decomposition subject to the following constraint:

$$\min \left[\sum_i r_i \right]$$

Parallel timestep is ideally K times the serial timestep: $\Delta t^p \approx K \Delta t^s$

Sectoring-Coloring to avoid boundary conflicts

Error Calculation: $bias = \langle m(\sigma_x) \rangle_x - \langle m(\sigma_x) \rangle$

Roadmap

The development of this algorithm will allow us to study the following processes:

1. Absorption and recombination of point defects at interfaces
2. Morphological and chemical stability of interfaces
3. Interface-driven mechanical response

- First objective: treatment of thermodynamics and displacements in the presence of incoherent interfaces.
- Second objective: Implementation of self-interstitial diffusion.
- Third objective: Fully parallelization of the code

Conclusions and Current Work

- We have developed a coupled MD-kMC algorithm that allows us to study heterogeneous systems.
- We can reach real times far beyond MD capabilities.
- We can take into account long-range fields (e.g. elastic fields).
- Localization of possible events via Voronoi tessellation.
- First nearest neighbors search for heterogeneous structures using Voronoi cell face sharing.
- Improvement of the physics:
 - Calculation of the barriers on the fly
 - Calculation of the prefactors.

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Vacancy Accumulation and Microstructure Evolution on a 2 degrees Twist Boundary in Cu

Dose rate = 10^{-1} V/A³s, $t_c = 1.265e-03$ s
 Dose rate = 10^1 V/A³s, $t_c = 4.244e-05$ s
 Dose rate = 10^2 V/A³s, $t_c = 8.500e-06$ s

Interface dislocations seem to be perfect sinks for vacancies. Vacancies accumulate at the dislocation constrictions but not at the dislocation intersections